

3.2x1.6 x0.8mm 940nm Infrared Chip SMD
OSI51206C1C

■Features

- Single chip
- Compact package outline
(L x W x T) of 3.2mm x 1.8mm x0.8mm
- Compatible to IR reflow soldering.
- Water Clear Lens Type

■Applications

- Automatic Control System
- Photo Detector
- Computer I/O Peripheral

■Absolute Maximum Rating

(T_a=25°C)

Item	Symbol	Value	Unit
DC Forward Current	I _F	30	mA
Pulse Forward Current*	I _{FP}	100	mA
Reverse Voltage	V _R	5	V
Power Dissipation	P _D	45	mW
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40~ +85	°C
Lead Soldering Temperature	T _{sol}	260°C/10sec	-

*Pulse width Max 0.1ms, Duty ratio max 1/10

■Electrical -Optical Characteristics

(T_a=25°C)

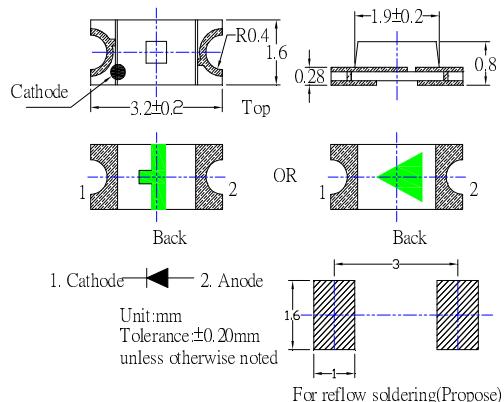
Item	Symbol	Condition	Min.	Typ.	Max.	Unit
DC Forward Voltage	V _F	I _F =20mA	-	1.2	1.5	V
DC Reverse Current	I _R	V _R =5V	-	-	10	μA
Peak Wavelength	λ _p	I _F =20mA	-	940	-	nm
Transmit Bandwidth	λ	I _F =20mA	-	45	-	nm
Radiant Intensity	I _e	I _F =20mA	0.5	1.3	-	mW/Sr
50% Power Angle	2θ _{1/2}	I _F =20mA	-	120	-	deg

*₁ Tolerance of measurements of Peak wavelength is ±1nm

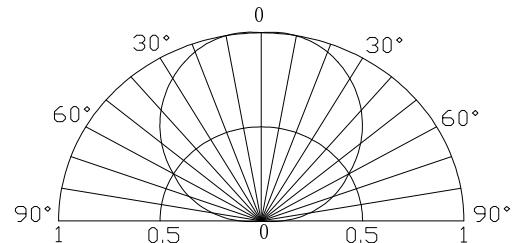
*₂ Tolerance of measurements of radiant intensity is ±15%

*₃ Tolerance of measurements of forward voltage is ±0.1V

■Outline Dimension



■Directivity



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